## NSN 5961-01-362-9717

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-362-9717 **Inclosure Material:** Glass **Overall Length:** 0.350 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.210 inches **Function For Which Designed:** Rectifier **End Application:** Milstar **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 14.0 forward voltage, dc **Current Rating Per Characteristic:** 1.00 microamperes forward current, average minor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Test Features:** Specially selected and tested for the milstar Irip program **Test Data Document:** 49956-g494565 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**